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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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# MCR218-2G, MCR218-4G, MCR218-6G



Expertise Applied | Answers Delivered

## Silicon Controlled Rectifiers

### Reverse Blocking Thyristors

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supplies; or wherever half-wave silicon gate-controlled, solid-state devices are needed.

#### Features

- Glass-Passivated Junctions
- Blocking Voltage to 400 Volts
- TO-220 Construction – Low Thermal Resistance, High Heat Dissipation and Durability

#### MAXIMUM RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

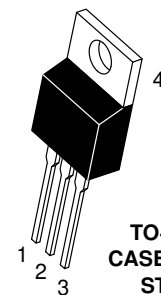
Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) ( $T_J = -40$ to $125^\circ\text{C}$ , Gate Open) MCR218-2G MCR218-4G MCR218-6G	$V_{\text{DRM}}$ , $V_{\text{RRM}}$	50 200 400	V
On-State RMS Current ( $180^\circ$ Conduction Angles; $T_C = 70^\circ\text{C}$ )	$I_{\text{T(RMS)}}$	8.0	A
Peak Non-repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, $T_J = 125^\circ\text{C}$ )	$I_{\text{TSM}}$	100	A
Circuit Fusing Considerations ( $t = 8.3$ ms)	$I^2t$	26	$\text{A}^2\text{s}$
Forward Peak Gate Power (Pulse Width $\leq 1.0$ $\mu\text{s}$ , $T_C = 70^\circ\text{C}$ )	$P_{\text{GM}}$	5.0	W
Forward Average Gate Power ( $t = 8.3$ ms, $T_C = 70^\circ\text{C}$ )	$P_{\text{G(AV)}}$	0.5	W
Forward Peak Gate Current (Pulse Width $\leq 1.0$ $\mu\text{s}$ , $T_C = 70^\circ\text{C}$ )	$I_{\text{GM}}$	2.0	A
Operating Junction Temperature Range	$T_J$	$-40$ to $+125$	$^\circ\text{C}$
Storage Temperature Range	$T_{\text{stg}}$	$-40$ to $+150$	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $V_{\text{DRM}}$  and  $V_{\text{RRM}}$  for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

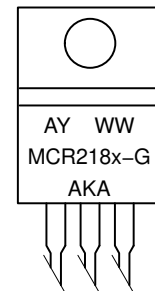
Littelfuse.com

**SCRs**  
**8 AMPERES RMS**  
**50 thru 400 VOLTS**



**TO-220AB**  
**CASE 221A-09**  
**STYLE 3**

#### MARKING DIAGRAM



A = Assembly Location  
Y = Year  
WW = Work Week  
MCR218x = Device Code  
x = 2, 4 or 6  
G = Pb-Free Package  
AKA = Diode Polarity

#### ORDERING INFORMATION

Device	Package	Shipping
MCR218-2G	TO220AB (Pb-Free)	500 Units/Bulk
MCR218-4G	TO220AB (Pb-Free)	500 Units/Bulk
MCR218-6G	TO220AB (Pb-Free)	500 Units/Bulk

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## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.0	$^{\circ}C/W$
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	$T_L$	260	$^{\circ}C$

## ELECTRICAL CHARACTERISTICS ( $T_J = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Peak Repetitive Forward or Reverse Blocking Current ( $V_{AK} = \text{Rated } V_{DRM} \text{ or } V_{RRM}, \text{ Gate Open}$ )	$I_{DRM}, I_{RRM}$	-	-	10	$\mu A$
$T_J = 25^{\circ}C$		-	-	2.0	$mA$
$T_J = 125^{\circ}C$		-	-		

### ON CHARACTERISTICS

Peak Forward On-State Voltage (Note 2) ( $I_{TM} = 16 \text{ A Peak}$ )	$V_{TM}$	-	1.5	1.8	V
Gate Trigger Current (Continuous dc) ( $V_D = 12 \text{ V}, R_L = 100 \text{ Ohms}$ )	$I_{GT}$	-	10	25	mA
Gate Trigger Voltage (Continuous dc) ( $V_D = 12 \text{ V}, R_L = 100 \text{ Ohms}$ )	$V_{GT}$	-	-	1.5	V
Gate Non-Trigger Voltage (Rated 12 V, $R_L = 100 \text{ Ohms}, T_J = 125^{\circ}C$ )	$V_{GD}$	0.2	-	-	V
Holding Current ( $V_D = 12 \text{ Vdc}, \text{ Initiating Current} = 200 \text{ mA}, \text{ Gate Open}$ )	$I_H$	-	16	30	mA

### DYNAMIC CHARACTERISTICS

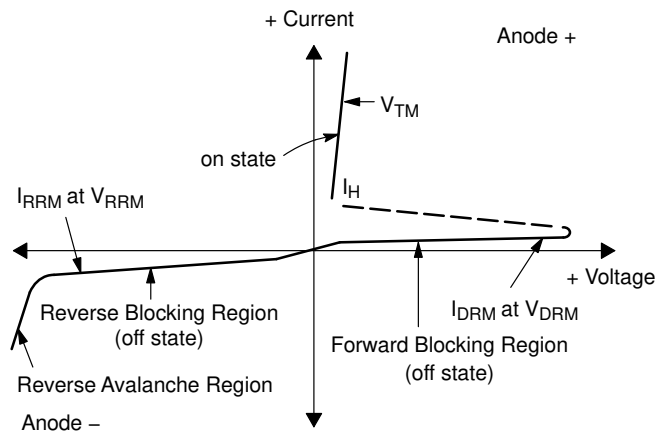
Critical Rate-of-Rise of Off-State Voltage ( $V_D = \text{Rated } V_{DRM}, \text{ Exponential Waveform, Gate Open, } T_J = 125^{\circ}C$ )	$dv/dt$	-	100	-	$V/\mu s$
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width = 1.0 ms, Duty Cycle  $\leq 2\%$ .

## Voltage Current Characteristic of SCR

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Off State Forward Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Off State Reverse Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Peak On State Voltage
$I_H$	Holding Current



# MCR218-2G, MCR218-4G, MCR218-6G

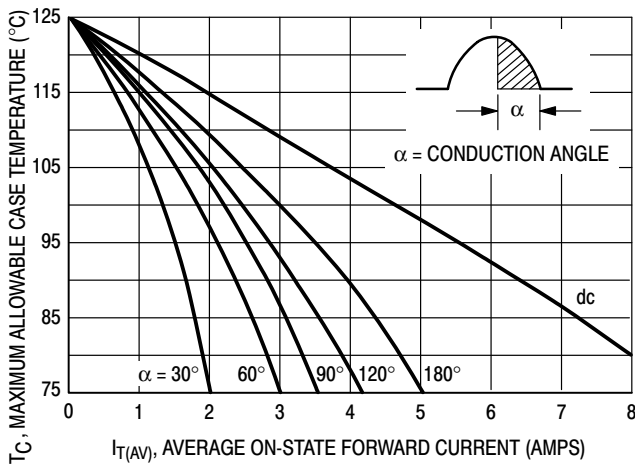


Figure 1. Current Derating

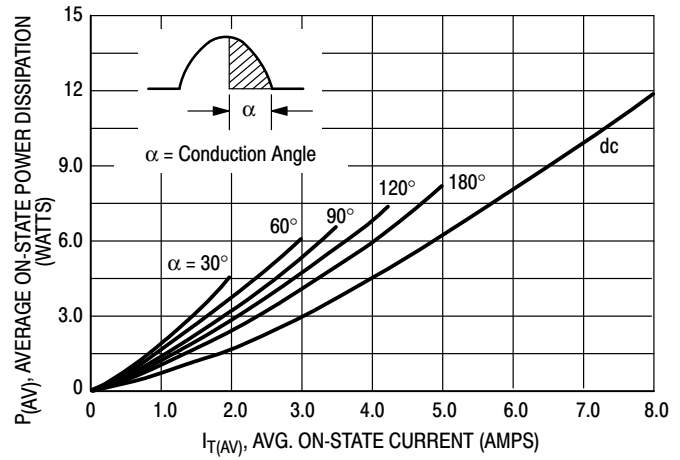


Figure 2. On-State Power Dissipation

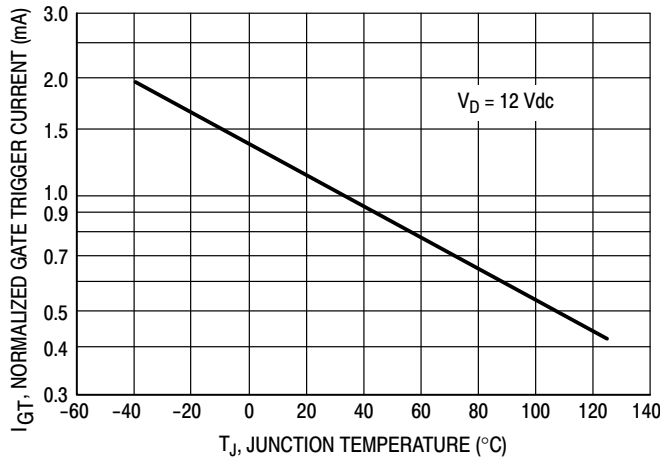


Figure 3. Typical Gate Trigger Current versus Temperature

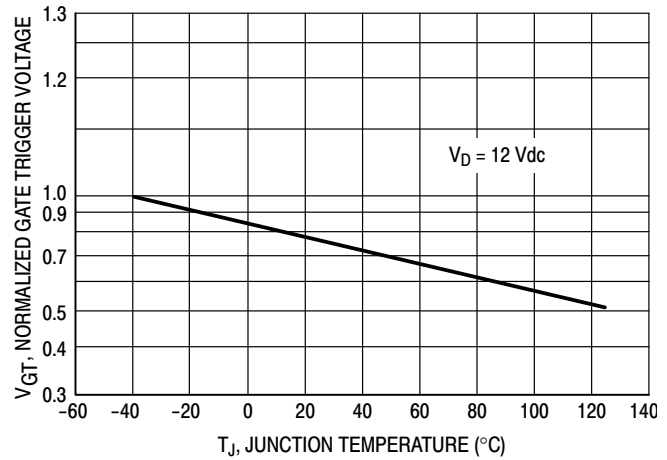


Figure 4. Typical Gate Trigger Voltage versus Temperature

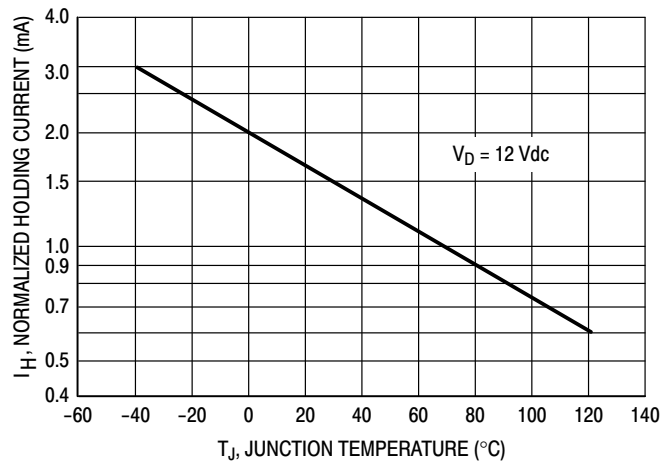
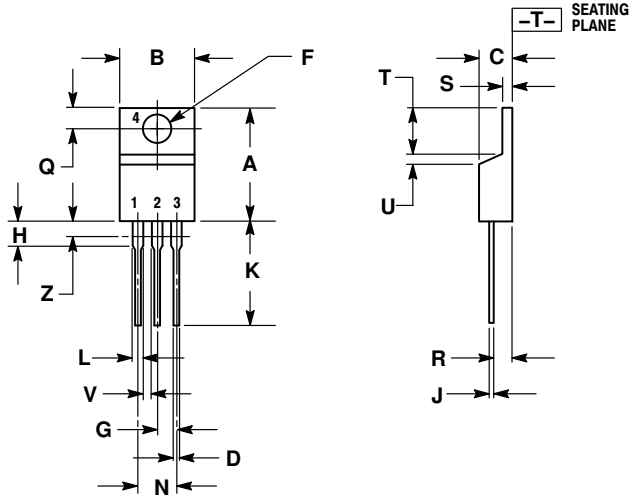


Figure 5. Typical Holding Current versus Temperature

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## PACKAGE DIMENSIONS

TO-220  
CASE 221A-09  
ISSUE AH



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.415	9.66	10.53
C	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 3:

- PIN 1. CATHODE  
2. ANODE  
3. GATE  
4. ANODE

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